

ON Semiconductor®

NC7SZU04 TinyLogic[®] UHS Unbuffered Inverter

Features

- Unbuffered for Crystal Oscillator and Analog Applications
- Balanced Output Drive: ±16mA at 4.5V V_{CC}
- Broad V_{CC} Operating Range: 1.65V to 5.5V
- Matches Performance of LCX Operated at 3.3V V_{CC}
- Low Quiescent Power: I_{CC}<2μA, V_{CC}=5.5V, T_A=25°C
- Ultra-Small MicroPak™ Packages
- Space-Saving SOT23 and SC70 Packages

Description

The NC7SZU04 is a single unbuffered inverter from ON Semiconductor's Ultra-High Speed series of TinyLogic®. The special purpose unbuffered circuit design is primarily intended for crystal oscillator or analog applications. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a broad $V_{\rm CC}$ operating range. The device is specified to operate over the 1.65V to 5.5V $V_{\rm CC}$ range.

Ordering Information

Part Number	Top Mark	Eco Status	Package	Packing Method
NC7SZU04M5X	7ZU4	RoHS	5-Lead SOT23, JEDEC MO-178 1.6mm	3000 Units on Tape & Reel
NC7SZU04P5X	ZU4	RoHS	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3000 Units on Tape & Reel
NC7SZU04L6X	C5	RoHS	6-Lead MicroPak™, 1.00mm Wide	5000 Units on Tape & Reel
NC7SZU04FHX	C5	Green	6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch	5000 Units on Tape & Reel

Connection Diagrams

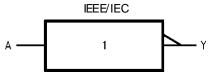


Figure 1. Logic Symbol

Pin Configurations

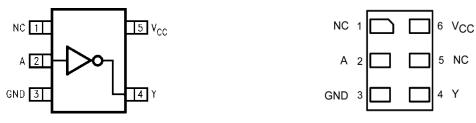


Figure 2. SC70 and SOT23 (Top View)

Figure 3. MicroPak (Top Through View)

Pin Definitions

Pin # SC70 / SOT23	Pin # MicroPak	Name	Description
1	1,5	NC	No Connect
2	2	А	Input
3	3	GND	Ground
4	4	Υ	Output
5	6	Vcc	Supply Voltage

Function Table

Y = /A

Inputs	Output
Α	Y
L	Н
Н	L

H = HIGH Logic Level

L = LOW Logic Level

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Para	ameter	Min.	Max.	Unit
Vcc	Supply Voltage		-0.5	6.0	V
V _{IN}	DC Input Voltage		-0.5	6.0	V
Vout	DC Output Voltage		-0.5	6.0	V
luz	DC Input Diode Current	V _{IN} < -0.5V		-50	mA
lık	DC Input Diode Current	V _{IN} > V _{CC} +5.0V		+20	IIIA
la	DC Output Diodo Current	V _{OUT} < -0.5V		-50	mA
loк	DC Output Diode Current	V _{OUT} > 0.5V, V _{CC} =GND		+50	IIIA
lout	DC Output Current			±50	mA
Icc or I _{GND}	DC V _{CC} or Ground Current			±100	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under B	ias		+150	°C
TL	Junction Lead Temperature (S	oldering, 10 Seconds)		+260	°C
		SOT-23		200	
D.	Dow or Dissinction at 1959C	SC70-5		150	
P_D	Power Dissipation at +85°C	MicroPak-6		130	mW
		MicroPak2-6		120	1
ESD	Human Body Model, JEDEC:JE	SD22-A114		4000	V
EOD	Charge Device Model, JEDEC:	JESD22-C101		2000	1 v

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V/	Supply Voltage Operating		1.65	5.50	V
Vcc	Supply Voltage Data Retention		1.50	5.50	7 V
V_{IN}	Input Voltage		0	5.5	V
Vout	Output Voltage		0	Vcc	V
T _A	Operating Temperature		-40	+85	°C
		SOT-23		300	
0	Thermal Resistance	SC70-5		425] ∘c/w
$\theta_{\sf JA}$	memai nesistance	MicroPak-6		500]
		MicroPak2-6		560	1

Note:

1. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

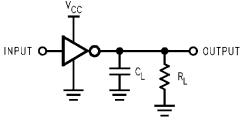
Cum hal	Parameter	V	Cons	ditions	T	_A =+25°	С	T _A =-40	to +85°C	Units	
Sym bol	Parameter	Vcc	Conc	uitions	Min.	Тур.	Max.	Min.	Max.	Units	
\/	HIGH Level	1.8 to 2.7			0.85V _{CC}			0.85V _{CC}		V	
V_{IH}	Input Voltage	3.0 to 5.5			0.80V _{CC}			0.80V _{CC}		V	
1/	LOW Level Input	1.8 to 2.7					0.15V _{CC}		0.15V _{CC}	V	
V_{IL}	Voltage	3.0 to 5.5					0.20V _{CC}		0.20V _{CC}	V	
		1.65			1.55	1.65		1.55			
		1.80			1.60	1.80		1.60			
		2.30	VIN=VIL, IOH	₊ =-100μA	2.10	2.30		2.10			
		3.00			2.70	3.00		2.70			
	HIGH Level	4.50			4.00	4.40		4.00		V	
V_{OH}	Output Voltage	1.65		I _{OH} =-4mA	1.29	1.52		1.29		V	
		2.30		I _{OH} =-4mA	1.90	2.14		1.90			
		3.00	V _{IN} =GND	I _{OH} =-8mA	2.40	2.75		2.40			
		3.00		I _{OH} =-12mA	2.30	2.61		2.30			
		4.50		I _{OH} =-16mA	3.80	4.13		3.80			
		1.65				0.00	0.10		0.10		
		1.80				0.00	0.20		0.20		
		2.30	VIN=VIH, IOI	_=100μA		0.00	0.20		0.20		
		3.00				0.00	0.30		0.30		
\ /	LOW Level	4.50				0.00	0.50		0.50	V	
V_{OL}	Output Voltage	1.65		I _{OL} =4mA		0.80	0.24		0.24	V	
		2.30		I _{OL} =4mA		0.10	0.30		0.30		
		3.00	$V_{IN} = V_{CC}$	I _{OL} =8mA		0.17	0.40		0.40		
		3.00		I _{OL} =12mA		0.25	0.55		0.55		
		4.50		I _{OL} =16mA		0.226	0.55		0.55		
I _{IN}	Input Leakage Current	0 to 5.5	V _{IN} =5.5V,	GND			±1		±10	μΑ	
Icc	Quiescent Supply Current	1.65 to 5.50	V _{IN} =5.5V,	GND			2		20	μΑ	
	Peak Supply	1.8				2					
ICCPEAK	Current in	2.5		n, V _{IN} =Adjust		4				mΔ	
ICCPEAK	Analog Operation	3.3	for Peak I	∞ Current		10				mA	
	Operation	5.0				30					

AC Electrical Characteristics

Symbol	Parameter	Vcc	Conditions	T,	_{A=+25°C}	;	T _A =-40	to +85°C	Units	Figure
Symbol	Farameter	VCC	Conditions	Min.	Тур.	Max.	Min.	Max.	Onics	rigure
		1.65		1.0		11.7	1.0	12.1		
		1.80		1.0		8.5	1.0	9.0		
		2.50 ± 0.20	$C_L=15pF$, $R_L=1M\Omega$,	0.8		6.2	0.8	6.5		
$t_{\text{PLH}}, t_{\text{PHL}}$	Propagation Delay	3.30 ± 0.30		0.5		4.5	0.5	4.8	ns	Figure 4 Figure 5
		5.00 ± 0.50		0.5		3.9	0.5	4.1		9
		3.30 ± 0.30	C _L =50pF,	1.0		6.0	1.0	6.5		
		5.00 ± 0.50	R _L =500Ω,	0.8		5.0	0.8	5.5		
C_{IN}	Input Capacitance	0.00			4.5				pF	
C _{PD}	Power Dissipation	3.30			6.3				pF	Figure 6
OPD	Capacitance ⁽²⁾	5.00			9.5				Ρı	i igule o

Note:

2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output lading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD}=(C_{PD})(V_{CC})(f_{IN})+(I_{CC}static).



Note:

- 3. C_L includes load and stray capacitance.
- 4. Input PRR=1.0MHz; tw=500ns

Figure 4. AC Test Circuit

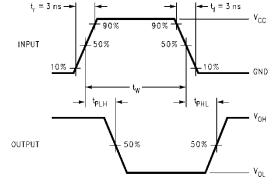
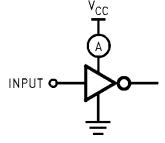


Figure 5. AC Waveforms



Note:

- 5. When operating the NC7SZU04's unbuffered output stage in its linear range, as in oscillator applications, care must be taken to observe maximum power rating for the device and package. The high drive nature of the design of the output stage results in substantial simultaneous conduction currents when the stage is in the linear region. See the ICCPEAK specification in the DC Electrical Characteristics table.
- 6. Input=AC Waveform; t_r=t_f=1.8ns; PRR=variable; Duty Cycle =50%.

Figure 6. Test Circuit

Physical Dimensions

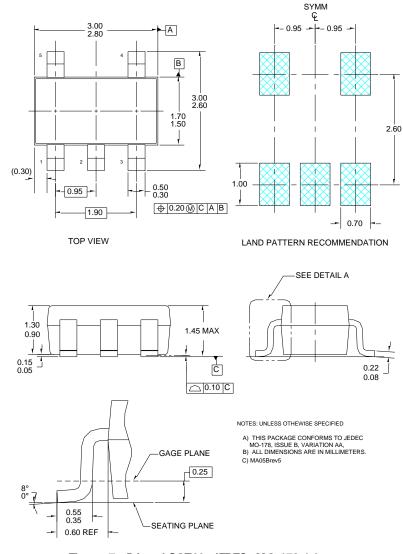


Figure 7. 5-Lead SOT23, JEDEC MO-178 1.6mm

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Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
	Leader (Start End)	125 (Typical)	Empty	Sealed
M5X	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed

Physical Dimensions

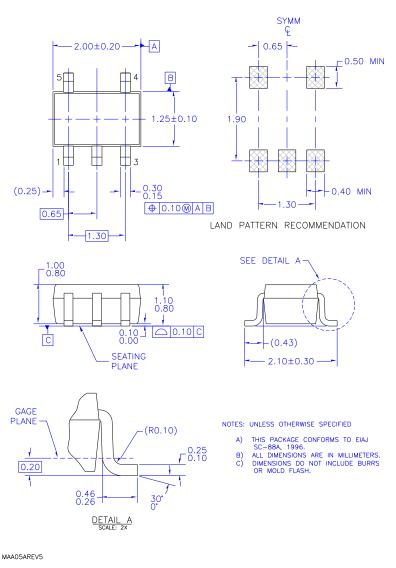
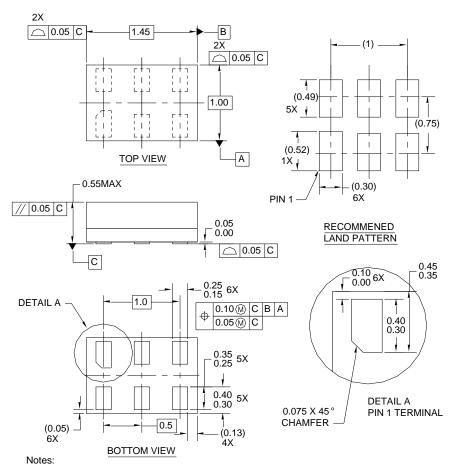


Figure 8. 5-Lead, SC70, EAJ SC-88a, 1.25mm Wide

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Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
	Leader (Start End)	125 (Typical)	Empty	Sealed
P5X	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed

Physical Dimensions



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Figure 9. 6-Lead, MicroPak™, 1.0mm Wide

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Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
	Leader (Start End)	125 (Typical)	Empty	Sealed
L6X	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed

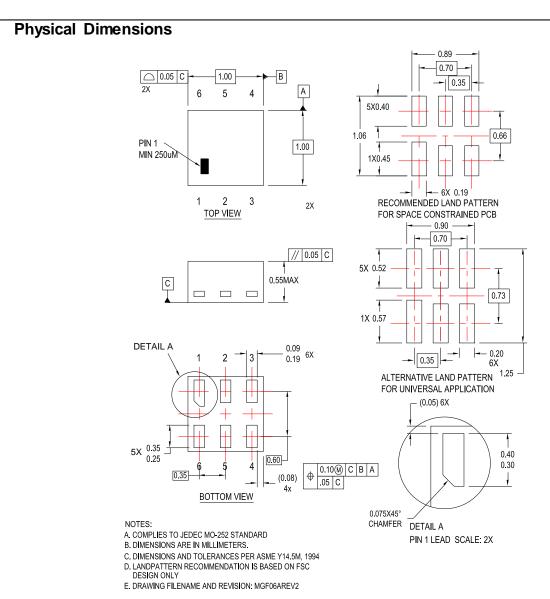


Figure 10.6-Lead, MicroPak2, 1x1mm Body, .35mm Pitch

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Package Designator	Tape Section	Cavity Number	Cavity Status	Cover Type Status
	Leader (Start End)	125 (Typical)	Empty	Sealed
FHX	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (Typical)	Empty	Sealed

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